

International
IR Rectifier

MURB1020CTPbF
MURB1020CT-1PbF

Ultrafast Rectifier

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

$$t_{rr} = 25\text{ns}$$

$$I_{F(AV)} = 10\text{Amp}$$

$$V_R = 200\text{V}$$

Description/ Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.


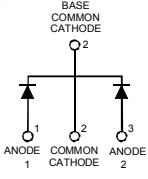

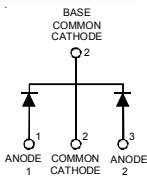
These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters		Max	Units
V_{RRM}	Peak Repetitive Peak Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current	5	A
	Total Device, (Rated V_R), $T_C = 149^\circ\text{C}$	10	
I_{FSM}	Non Repetitive Peak Surge Current	50	
I_{FM}	Peak Repetitive Forward Current	10	
	(Rated V_R , Square wave, 20 KHz), $T_C = 149^\circ\text{C}$		
T_J, T_{STG}	Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

Case Styles

MURB1020CTPbF	MURB1020CT-1PbF
  D²PAK	  TO-262

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _r Breakdown Voltage, Blocking Voltage	200	-	-	V	I _R = 100μA
V _F Forward Voltage	-	0.87	0.99	V	I _F = 5A, T _J = 125°C
	-	1.02	1.20	V	I _F = 10A, T _J = 125°C
	-	1.12	1.25	V	I _F = 10A, T _J = 25°C
I _R Reverse Leakage Current	-	-	10	μA	V _R = V _R Rated
	-	-	250	μA	T _J = 150°C, V _R = V _R Rated
C _T Junction Capacitance	-	8	-	pF	V _R = 200V
L _S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	-	35	ns	I _F = 1.0A, di _F /dt = 50A/μs, V _R = 30V
	-	-	25		I _F = 0.5A, I _R = 1.0A, I _{REC} = 0.25A
	-	24	-	35	T _J = 25°C
					T _J = 125°C
I _{RRM} Peak Recovery Current	-	3.3	-	A	T _J = 25°C
	-	5.0	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	33	-	nC	T _J = 25°C
	-	76	-		T _J = 125°C

I_F = 5A
V_R = 160V
di_F /dt = 200A/μs

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	175	
R _{thJC} Thermal Resistance, Junction to Case Per Leg	-	-	5	°C/W
R _{thJA} Thermal Resistance, Junction to Ambient Per Leg	-	-	50	
R _{thCS} ^① Thermal Resistance, Case to Heatsink	-	0.5	-	
Wt Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in
Marking Device	MURB1020CT		Case style D ² Pak	
	MURB1020CT-1		Case style TO-262	

① Mounting Surface, Flat, Smooth and Greased

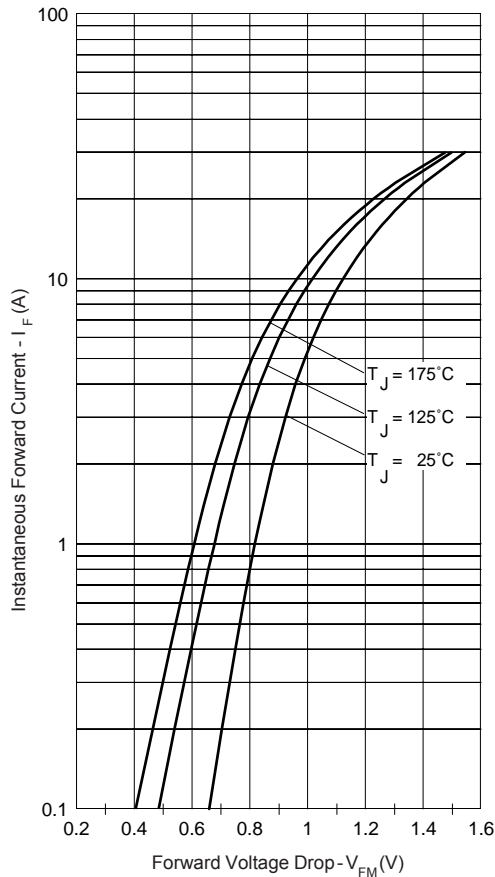


Fig. 1 - Typical Forward Voltage Drop Characteristics

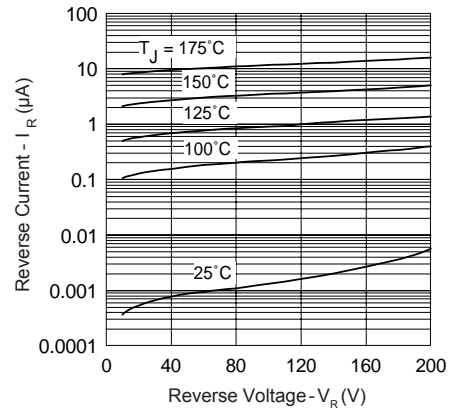


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

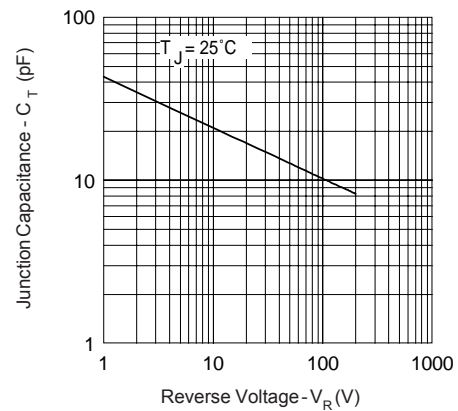


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

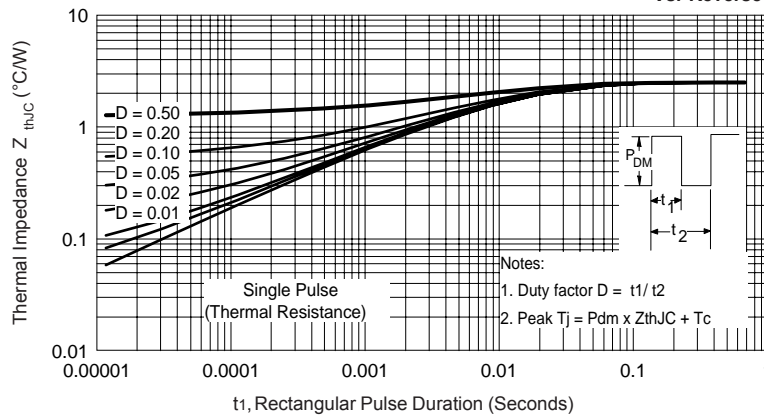


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

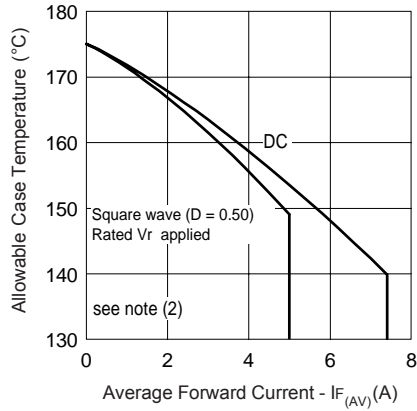


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

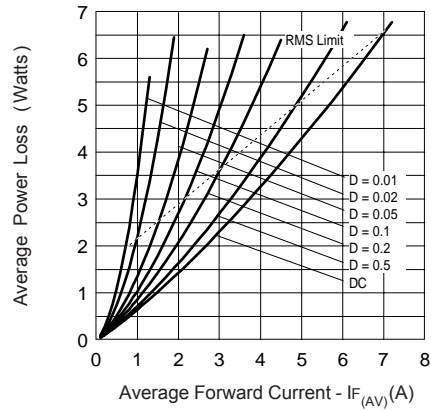


Fig. 6 - Forward Power Loss Characteristics

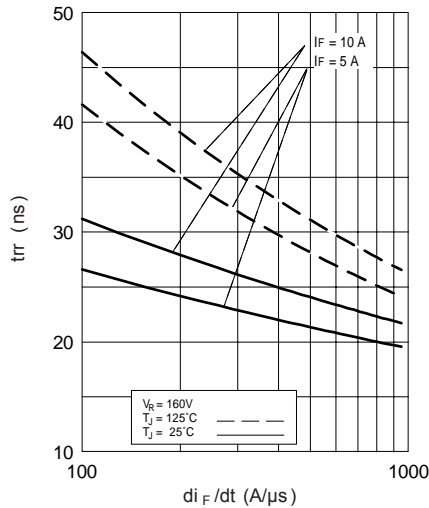


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

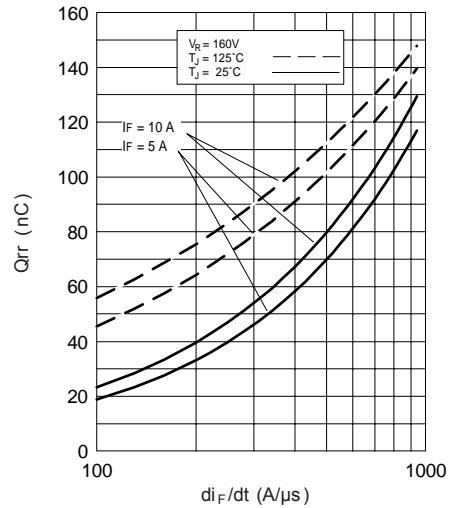


Fig. 8 - Typical Stored Charge vs. di_F/dt

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

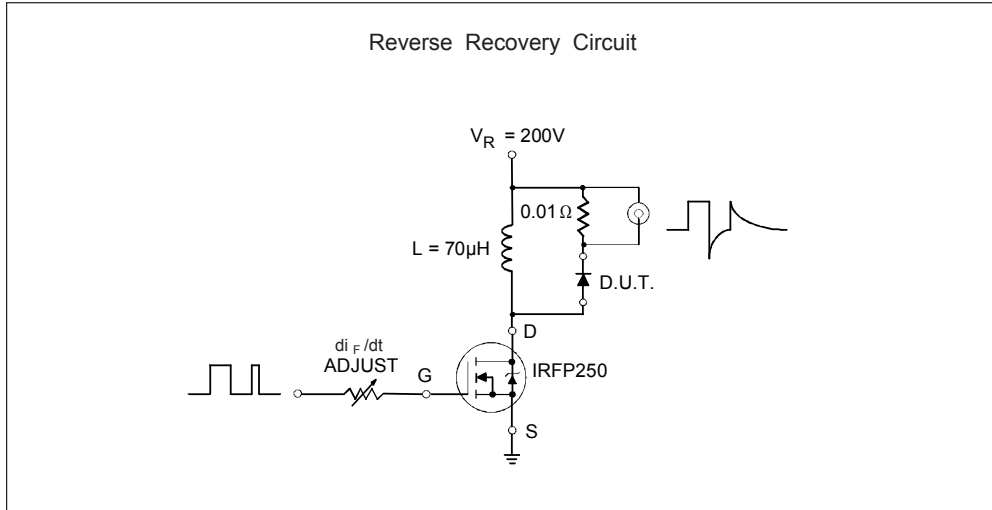


Fig. 9- Reverse Recovery Parameter Test Circuit

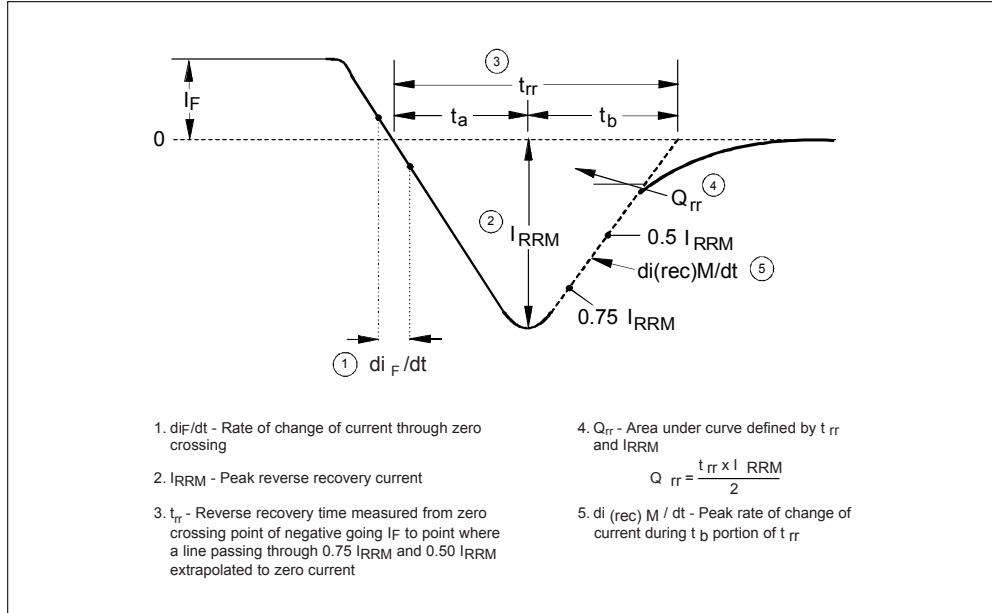
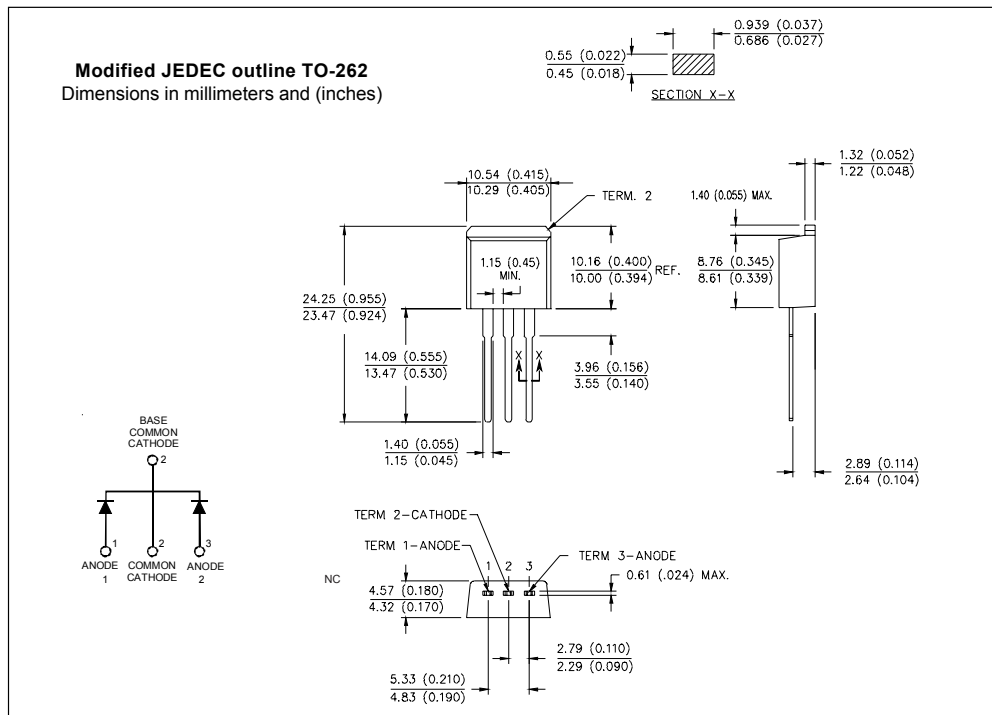
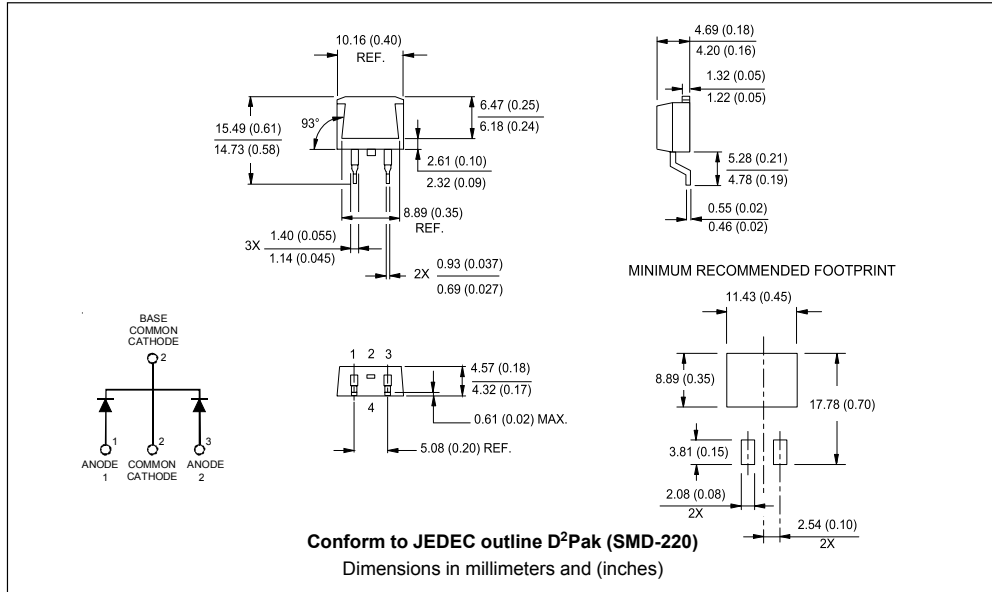


Fig. 10 - Reverse Recovery Waveform and Definitions

Outlines Table

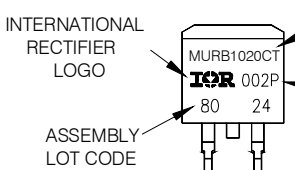


Part Marking Information

D²PAK

EXAMPLE: THIS IS A MURB1020CT
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

Note: "P" in assembly line position indicates "Lead-Free"



INTERNATIONAL RECTIFIER LOGO

ASSEMBLY LOT CODE

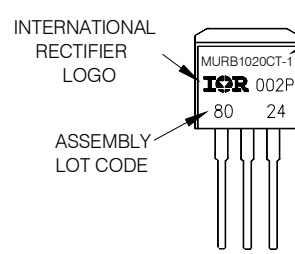
PART NUMBER

DATE CODE
YEAR 0 = 2000
WEEK 02
P = LEAD-FREE

TO-262

EXAMPLE: THIS IS A MURB1020CT-1
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

Note: "P" in assembly line position indicates "Lead-Free"



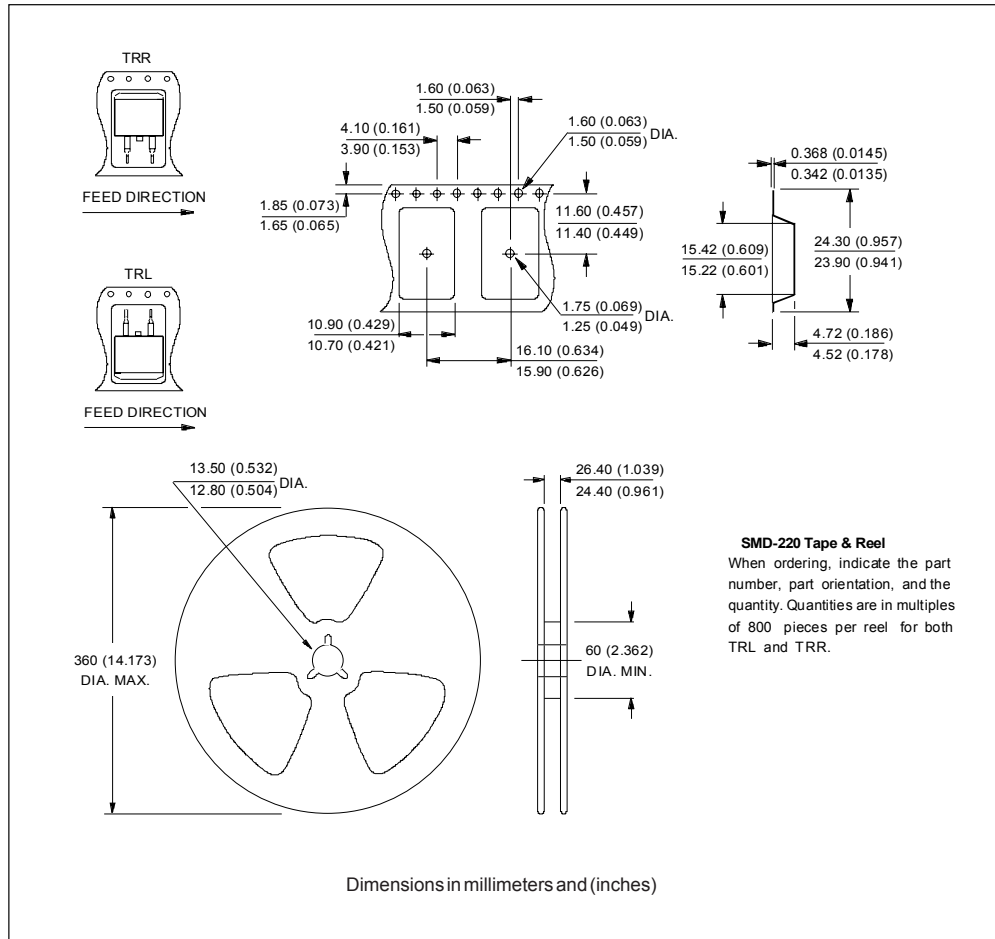
INTERNATIONAL RECTIFIER LOGO

ASSEMBLY LOT CODE

PART NUMBER

DATE CODE
YEAR 0 = 2000
WEEK 02
P = LEAD-FREE

Tape & Reel Information



Ordering Information Table

Device Code	MUR	B	10	20	CT	-1	TRL	PbF
	①	②	③	④	⑤	⑥	⑦	⑧
1	-							
		2						
			3					
				4				
					5			
						6		
							7	
								8

1	-	Ultrafast MUR Series
2	-	B = D ² Pak/ TO-262
3	-	Current Rating (10 = 10A)
4	-	Voltage Rating (20 = 200V)
5	-	CT = Center Tap (Dual) TO-220 /D ² PAK/ TO-262
6	-	-1 = TO-262
7	-	<ul style="list-style-type: none"> • none = Tube (50 pieces) • TRL = Tape & Reel (Left Oriented, for D²PAk package) • TRR = Tape & Reel (Right Oriented, for D²PAk package)
8	-	<ul style="list-style-type: none"> • none = Standard Production • PbF = Lead-Free

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level and Lead-Free.
 Qualification Standards can be found on IR's Web site.